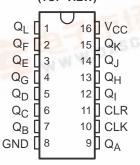
捷多邦,专业PCB打**多N54LV4040A&SN74LV4040A** 12-BIT ASYNCHRONOUS BINARY COUNTERS

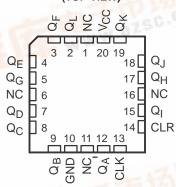
SCES226B - APRIL 1999 - REVISED MAY 2000

- **EPIC** ™ (Enhanced-Performance Implanted **CMOS) Process**
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$
- Typical V_{OHV} (Output V_{OH} Undershoot) >2.3 V at $V_{CC} = 3.3$ V, $T_A = 25$ °C
- 2-V to 5.5-V V_{CC} Operation
- Support Mixed-Mode Voltage Operation on **All Ports**
- High On-Off Output-Voltage Ratio
- Low Crosstalk Between Switches
- **Individual Switch Controls**
- **Extremely Low Input Current**
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- Package Options Include Plastic Small-Outline (D, NS), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Ceramic (J) DIPs

SN54LV4040A . . . J OR W PACKAGE SN74LV4040A . . . D, DB, DGV, NS, OR PW PACKAGE (TOP VIEW)



SN54LV4040A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

description

The 'LV4040A devices are 12-bit asynchronous binary counters with the outputs of all stages available externally. A high level at the clear (CLR) input asynchronously clears the counter and resets all outputs low. The count is advanced on a high-to-low transition at the clock (CLK) input. Applications include time-delay circuits, counter controls, and frequency-dividing circuits.

The SN54LV4040A is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74LV4040A is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each buffer)

INP	UTS	FUNCTION
CLK	CLR	FUNCTION
1	L	No change
\	L	Advance to next stage
X	Н	All outputs L

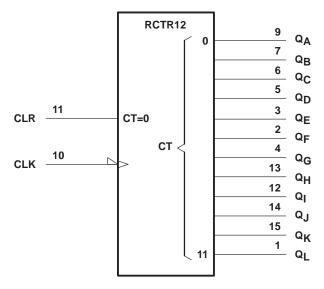
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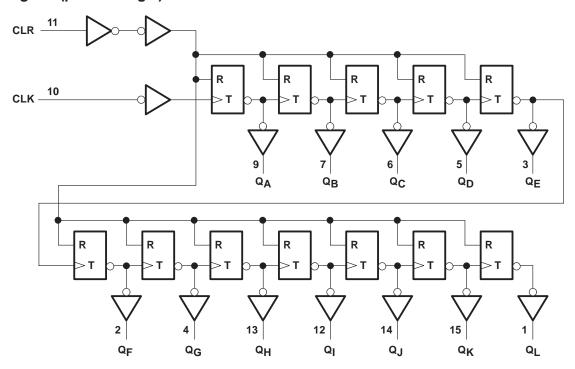
Cis a trademark of Texas Instruments

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, DB, DGV, J, NS, PW, and W packages.

logic diagram (positive logic)



Pin numbers shown are for the D, DB, DGV, J, NS, PW, and W packages.



SCES226B - APRIL 1999 - REVISED MAY 2000

absolute maximum ratings over operating free-air temperature range†

Supply voltage range, V _{CC}		0.5 V to 7 V
Input voltage range, V _I (see Note 1)		
Voltage range applied to any output in the high		
or power-off state, V _O (see Note 1)		–0.5 V to 7 V
Output voltage range, VO (see Notes 1 and 2)		
Input clamp current, I_{IK} ($V_I < 0$)		
Output clamp current, IOK (VO < 0 or VO > VC	CC)	±50 mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$		±25 mA
Continuous current through V _{CC} or GND		±50 mA
Package thermal impedance, θ _{JA} (see Note 3): D package	73°C/W
	DB package	82°C/W
	DGV package	120°C/W
	NS package	64°C/W
	PW package	
Storage temperature range, T _{stq}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. This value is limited to 5.5 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51.

SCES226B - APRIL 1999 - REVISED MAY 2000

recommended operating conditions (see Note 4)

			SN54L	V4040A	SN74L	V4040A	UNIT
			MIN	MAX	MIN	MAX	UNII
Vcc	Supply voltage		2	5.5	2	5.5	V
		V _{CC} = 2 V	1.5		1.5		
V	High level input voltage	V _{CC} = 2.3 V to 2.7 V	V _{CC} ×0.7		V _{CC} × 0.7		V
VIH	High-level input voltage	V _{CC} = 3 V to 3.6 V	V _{CC} ×0.7		$V_{CC} \times 0.7$		V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	V _{CC} × 0.7		$V_{CC} \times 0.7$		
		V _{CC} = 2 V		0.5		0.5	
VII	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	V
۷IL	Low-level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		V _{CC} ×0.3		$V_{CC} \times 0.3$	
٧ _I	Input voltage		0	5.5	0	5.5	V
٧o	Output voltage		0	⁴ √VCC	0	VCC	V
		V _{CC} = 2 V		-50		-50	μΑ
lou	High-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	20	-2		-2	
ЮН	riigri-ievei output current	V _{CC} = 3 V to 3.6 V	30	-6		-6	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2	-12		-12	
		V _{CC} = 2 V		50		50	μΑ
lai	Low-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2		2	
IOL	Low-level output current	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		6		6	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		12		12	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0	200	0	200	
$\Delta t/\Delta v$	Input transition rise or fall rate	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	0	100	0	100	ns/V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0	20	0	20	
TA	Operating free-air temperature	<u> </u>	-55	125	-40	85	°C

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

SCES226B - APRIL 1999 - REVISED MAY 2000

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	,,	SN54	LV4040A	\	SN74	LV4040	4	UNIT
PARAMETER	TEST CONDITIONS	v _{CC}	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
	I _{OH} = -50 μA	2 V to 5.5 V	V _{CC} -0.1			V _{CC} -0.1			
\/o	$I_{OH} = -2 \text{ mA}$	2.3 V	2			2			V
Voн	I _{OH} = -6 mA	3 V	2.48			2.48			V
	I _{OH} = -12 mA	4.5 V	3.8	Jaj.		3.8			
	I _{OL} = 50 μA	2 V to 5.5 V		Je J	0.1			0.1	
\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	I _{OL} = 2 mA	2.3 V		,0	0.4			0.4	V
VOL	I _{OL} = 6 mA	3 V		Ç)	0.44			0.44	V
	I _{OL} = 12 mA	4.5 V	90		0.55			0.55	
lį	$V_I = V_{CC}$ or GND	0 V to 5.5 V	Q.		±1			±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			20			20	μΑ
l _{off}	V_I or $V_O = 0$ to 5.5 V	0 V			5			5	μΑ
Ci	V _I = V _{CC} or GND	3.3 V		1.9			1.9		pF

timing requirements over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

			T _A =	25°C	SN54LV	4040A	SN74LV	4040A	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	UNIT
	Pulse duration	CLK high or low	7		7	10.74	7		no
ι _W	ruise duration	CLR high	6.5		6.5	III.	6.5		ns
t _{su}	Setup time	CLR inactive before CLK↓	6.5		6.5		6.5		ns

timing requirements over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

			$T_A = 2$	25°C	SN54LV	4040A	SN74LV4040A		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _w Pulse duration		CLK high or low	5		5	N. W	5		ns
τ _W	ruise duration	CLR high	5		- (5)		5		115
t _{su}	Setup time	CLR inactive before CLK↓	5		5		5		ns

timing requirements over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

	CLK high or low	T _A = 25°C		SN54LV	4040A	SN74LV4040A		UNIT	
			MIN	MAX	MIN	MAX	MIN	MAX	UNIT
Ţ.	Pulse duration	CLK high or low	5		500		5		no
t _W	ruise duration	CLR high	5		5	11/2	5		ns
t _{su}	Setup time	CLR inactive before CLK↓	5		5		5		ns



SCES226B - APRIL 1999 - REVISED MAY 2000

switching characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	ղ = 25°C	;	SN54LV	4040A	SN74LV	4040A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
4			C _L = 15 pF	50*	115*		40*		40		MHz
fmax			C _L = 50 pF	40	95		35	3	35		IVITIZ
^t PLH	CLK	0.	C _I = 15 pF		8.7*	19.4*	1*	23*	1	23	ns
^t PHL	CLK	Q _A	GE = 13 bis		8.7*	19.4*	1*	23*	1	23	115
^t PHL	CLR	Any Q	C _L = 15 pF		9.3*	19.9*	1*	24*	1	24	ns
^t PLH	CLK		C _I = 50 pF		10.5	24.1	77/	28	1	28	ns
^t PHL	CLK	Q_{A}	CL = 30 pr		10.5	24.1	01	28	1	28	115
^t PHL	CLR	Any Q	$C_L = 50 pF$		11.7	24.5	Q 1	28	1	28	ns
Δt_{pd}	Qn	Q _{n+1}	C _L = 50 pF		1.7	5.9		7		7	ns

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	Δ = 25°C	;	SN54LV	4040A	SN74LV	4040A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			C _L = 15 pF	75*	160*		75*		75		MHz
fmax			C _L = 50 pF	55	130		50	3	50		IVITIZ
^t PLH	01.14		C _I = 15 pF		6.1*	11.9*	1*	14*	1	14	ns
^t PHL	CLK	Q_A	CL = 13 pr		6.1*	11.9*	1*	14*	1	14	115
^t PHL	CLR	Any Q	C _L = 15 pF		7.1*	12.8*	1*/	15*	1	15	ns
t _{PLH}	01.14		C 50 pE		7.5	15.4	77/	17.5	1	17.5	ns
^t PHL	CLK	Q_A	C _L = 50 pF		7.5	15.4	0 1	17.5	1	17.5	115
^t PHL	CLR	Any Q	C _L = 50 pF		9	16.3	Q 1	18.5	1	18.5	ns
Δt_{pd}	Qn	Q _{n+1}	C _L = 50 pF		1.2	4.4		5		5	ns

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	4 = 25°C	;	SN54LV	4040A	SN74LV	4040A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
f			C _L = 15 pF	150*	235*		125*		125		MHz
f _{max}			C _L = 50 pF	95	185		80	3	80		IVITIZ
t _{PLH}	01.14	_	C _I = 15 pF		4.2*	7.3*	1*	8.5*	1	8.5	20
t _{PHL}	CLK	Q_A	CL = 15 pr		4.2*	7.3*	1*	8.5*	1	8.5	ns
t _{PHL}	CLR	Any Q	C _L = 15 pF		5.3*	8.6*	1*/	10*	1	10	ns
^t PLH		_	C _I = 50 pF		5.3	9.3	77	10.5	1	10.5	20
^t PHL	CLK	Q _A	CL = 50 pr		5.3	9.3	01	10.5	1	10.5	ns
t _{PHL}	CLR	Any Q	C _L = 50 pF		6.8	10.6	Q 1	12	1	12	ns
Δt_{pd}	Q _n	Q _{n+1}	C _L = 50 pF		0.8	3.1		3.5		3.5	ns

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.



SCES226B - APRIL 1999 - REVISED MAY 2000

noise characteristics, V_{CC} = 3.3 V, C_L = 50 pF, T_A = 25°C (see Note 5)

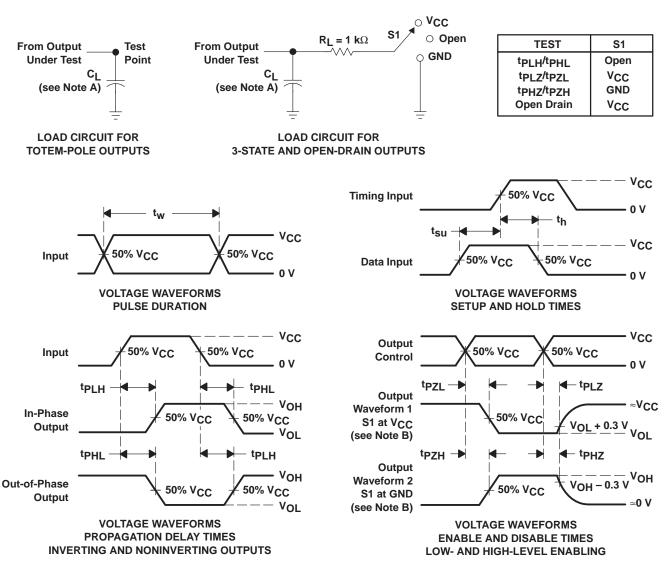
	PARAMETER	SN7	4LV404	0A	UNIT
	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic VOL		0.5	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.5	-0.8	V
V _{IH(D)}	High-level dynamic input voltage	2.31			V
V _{IL(D)}	Low-level dynamic input voltage			0.99	V

NOTE 5: Characteristics are for surface-mount packages only.

operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	VCC	TYP	UNIT
Card		C _I = 50 pF, f = 10 MHz	3.3 V	11.9	PΓ
Сра	i ower dissipation capacitance	CL = 50 pF,	5 V	13.1	ρι

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \,\Omega$, $t_f \leq 3$ ns. $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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